National Semiconductor

November 1994

54F/74F243
Quad Bus Transceiver with TRI-STATE® Outputs

General Description

The ’F243 is a quad bus transmitter/receiver designed for 4-line asynchronous 2-way data communications between data busses.

Features

- 2-Way asynchronous data bus communication
- Input clamp diodes limit high-speed termination effects
- Guaranteed 4000V minimum ESD protection

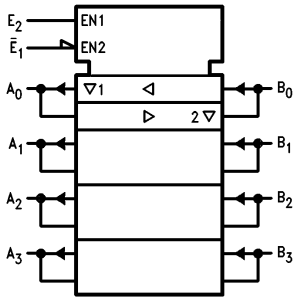
Commercial	Military	Package Number	Package Description
	54F243DM (Note 2)	J14A	14-Lead Ceramic Dual-In-Line
74F243SC (Note 1)		M14A	14-Lead (0.150″ Wide) Molded Small Outline, JEDEC
	54F243FM (Note 2)	W14B	14-Lead Cerpack
	54F243LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Note 1: Devices also available in 13″ reel. Use Suffix = SCX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

Logic Symbol

IEEE/IEC



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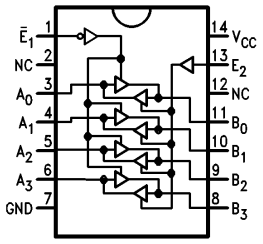
Connection Diagrams

Pin Assignment for DIP, SOIC and Flatpak



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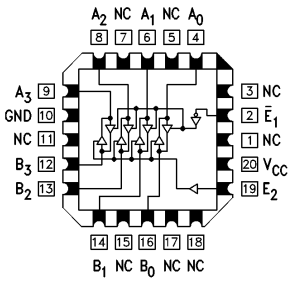
Pin Assignment for LCC



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RRD-B30M105/Printed in U. S. A.

Unit Loading/Fan Out

Pin Names	Description	54F/74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{E}_1$	Enable Input (Active LOW)	1.0/1.67	20 μA/−1 mA
E_2	Enable Input (Active HIGH)	1.0/1.67	20 μA/−1 mA
A_n, B_n	Inputs	3.5/2.67	70 μA/−1.6 mA
	Outputs	600/106.6(80)	−12 mA/64 mA(48 mA)

Truth Table

Inputs		Inputs/Outputs	
$\overline{E}_1$	E_2	A_n	B_n
L	L	Input	B = A
L	H	N/A	N/A
H	L	Z	Z
H	H	A = B	Input

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
N/A = Not Allowed

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
TRI-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55°C to +125°C
Commercial	0°C to +70°C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter		54F/74F Min	54F/74F Typ	54F/74F Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	54F 10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA (A_n, B_n)
		54F 10% V_{CC}	2.0					I_{OH} = −12 mA (A_n, B_n)
		74F 10% V_{CC}	2.4					I_{OH} = −3 mA (A_n, B_n)
		74F 10% V_{CC}	2.0					I_{OH} = −15 mA (A_n, B_n)
		74F 5% V_{CC}	2.7					I_{OH} = −3 mA (A_n, B_n)
V_{OL}	Output LOW Voltage	54F 10% V_{CC}			0.55	V	Min	I_{OL} = 48 mA (A_n, B_n)
		74F 10% V_{CC}			0.55			I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current	54F			20.0	μA	Max	V_{IN} = 2.7V
		74F			5.0			
I_{BVI}	Input HIGH Current Breakdown Test	54F			100	μA	Max	V_{IN} = 7.0V ($\overline{E}_1$, E_2)
		74F			7.0			
I_{BVIT}	Input HIGH Current Breakdown (I/O)	54F			1.0	mA	Max	V_{IN} = 5.5V (A_n, B_n)
		74F			0.5			
I_{CEX}	Output HIGH Leakage Current	54F			250	μA	Max	V_{OUT} = V_{CC}
		74F			50			
V_{ID}	Input Leakage Test	74F	4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current	74F			3.75	μA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−1.0	mA	Max	V_{IN} = 0.5V ($\overline{E}_1$, E_2)
I_{IH} + I_{OZH}	Output Leakage Current				70	μA	Max	V_{OUT} = 2.7V (A_n, B_n)
I_{IL} + I_{OZL}	Output Leakage Current				−1.6	mA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CCH}	Power Supply Current			64	80	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			64	90	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			71	90	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

Symbol	Parameter	74F			54F		74F		Units
		$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			T_A, V_{CC} = Mil, $C_L = 50$ pF		T_A, V_{CC} = Com, $C_L = 50$ pF		
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.0	5.2	2.0	6.5	2.0	6.2	ns
t_{PHL}	A_n to B_n, B_n to A_n	2.5	4.0	5.2	2.0	8.5	2.0	6.5	
t_{PZH}	Output Enable Time	2.0	4.3	5.7	2.0	8.0	2.0	6.7	ns
t_{PZL}	$\overline{E}_1$ to B_n, E_2 to A_n	2.0	5.8	7.5	2.0	10.5	2.0	8.5	
t_{PHZ}	Output Disable Time	2.0	4.5	6.0	1.5	7.5	1.5	7.0	
t_{PLZ}	$\overline{E}_1$ to B_n, E_2 to A_n	2.0	4.5	6.0	2.0	8.5	2.0	7.0	

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

74F 243 S C X

Temperature Range Family
- 74F = Commercial
- 54F = Military

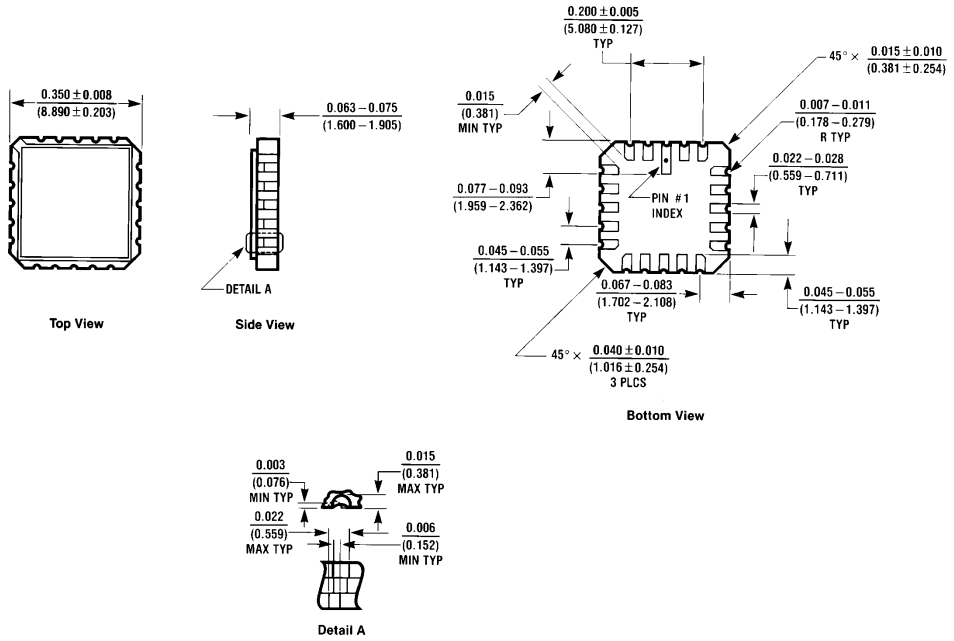
Device Type

Package Code
- D = Ceramic DIP
- F = Flatpak
- L = Leadless Chip Carrier (LCC)
- S = Small Outline SOIC JEDEC

Temperature Range
- C = Commercial (0°C to +70°C)
- M = Military (−55°C to +125°C)

Special Variations
- QB = Military grade device with environmental and burn-in processing
- X = Devices shipped in 13″ reel

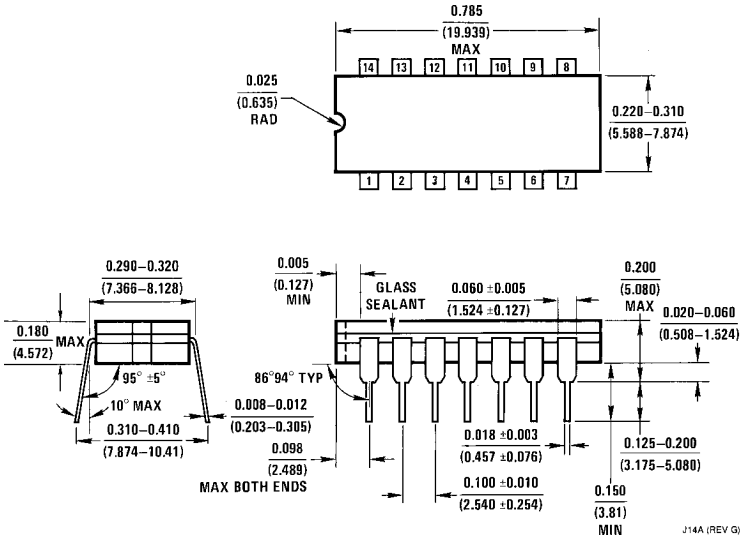
Physical Dimensions inches (millimeters)



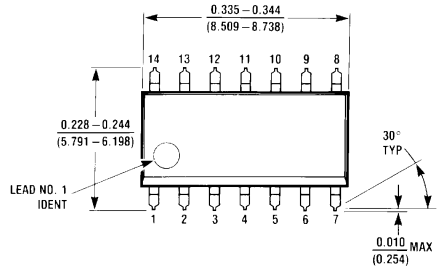
E20A (REV D)

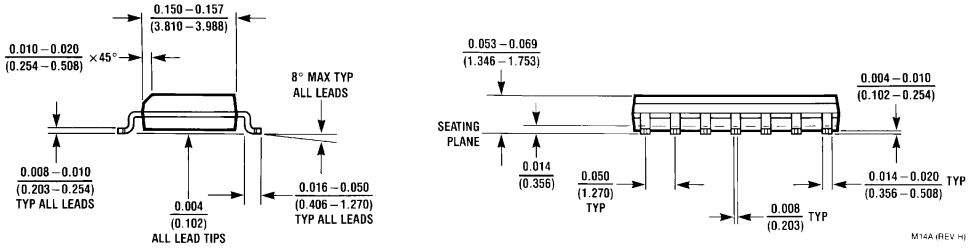
20-Lead Ceramic Leadless Chip Carrier (L)
NS Package Number E20A

Physical Dimensions inches (millimeters) (Continued)



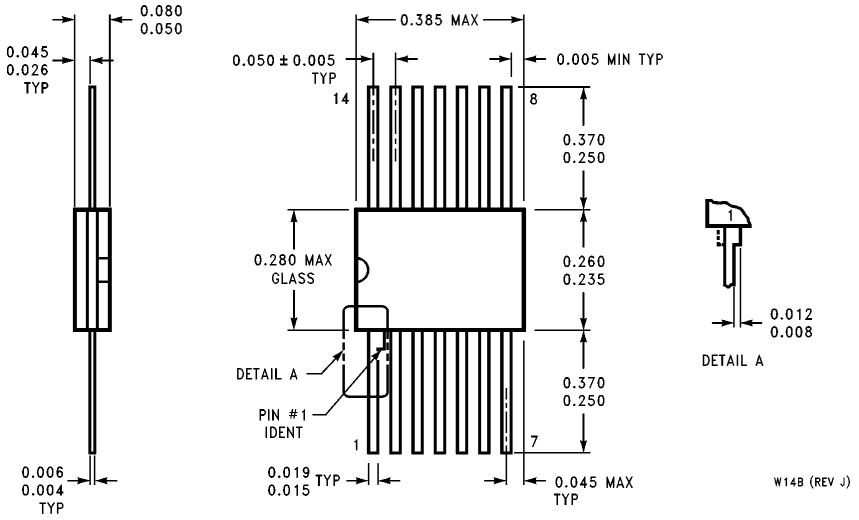
14-Lead Ceramic Dual-In-Line Package (D)
NS Package Number J14A





14-Lead (0.150″ Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M14A

Physical Dimensions inches (millimeters) (Continued)



14-Lead Ceramic Flatpak (F)
NS Package Number W14B

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National Semiconductor Corporation
1111 West Bardin Road
Arlington, TX 76017
Tel: 1(800) 272-9959
Fax: 1(800) 737-7018

National Semiconductor Europe
Fax: (+49) 0-180-530 85 86
Email: cnjwge@tevm2.nsc.com
Deutsch Tel: (+49) 0-180-530 85 85
English Tel: (+49) 0-180-532 78 32
Français Tel: (+49) 0-180-532 93 58
Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.
Tsimshatsui, Kowloon
Hong Kong
Tel: (852) 2737-1600
Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408

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Тел: +7 (812) 336 43 04 (многоканальный)
Email: org@lifeelectronics.ru

www.lifeelectronics.ru